AUTOMOTIVI GRADE

COMPLIANT

HALOGEN FREE



Vishay General Semiconductor

Surface-Mount High Voltage Rectifiers



DO-218AB



PRIMARY CHARACTERISTICS				
I _{F(AV)}	50 A			
V_{RRM}	1200 V			
I _{FSM}	700 A			
V_F at $I_F = 50 \text{ A (T}_J = 125 ^{\circ}\text{C)}$	1.08			
I _R	10 μΑ			
E _{AS}	20 mJ			
T _J max.	175 °C			
Package	DO-218AB			
Circuit configurations	Single			

FEATURES

- · Excellent heat dissipation
- Oxide planar chip junction
- High surge current capability
- Ultra-low forward conduction
- High junction temperature capability
- High ESD capability
- High avalanche capability
- Meets MSL level 1, per J-STD-02, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- Fly-wheeling diode for big power motor in EV/HEV
- · Single or three phase bridge rectification circuit
- High voltage block diode

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

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AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix

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Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SE50124	UNIT		
Device marking code		SE50124			
Maximum repetitive peak reverse voltage	V_{RRM}	1200	V		
Maximum DC forward current	I _F ⁽¹⁾	50	^		
	I _F ⁽²⁾	4.2	А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	700	Α		
8 x 20 µs wave form by 10 surge pulses in 10 minutes	I _{FSM}	3500	Α		
Typical Non-repetitive Avalanche energy at I _{AS} = 1A, T _J = 25 °C	E _{AS}	20	mJ		
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175	°C		

Notes

(1) Mounted on aluminum PCB 30 mm x 30 mm with aluminum heatsink

(2) Free air, mounted on recommended copper pad area



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ELECTRICAL CHARACTERISTICS (T _J = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 25 A	T _J = 25 °C		1.02	-	V
	I _F = 50 A		V _E (1)	1.16	1.32	
	I _F = 25 A	- T _J = 125 °C	V _F (·)	0.92	=	
	I _F = 50 A			1.08	-	
Reverse current	Patad V	$T_{J} = 25 ^{\circ}\text{C}$	I _R ⁽²⁾	-	10	μА
	Rated V _R	T _J = 125 °C	IR (-)	30	=	
Typical junction capacitance	400 V, 1 MHz		CJ	35	-	pF

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °c unless otherwise noted)				
PARAMETER SYMBOL SE50124				
Typical thermal registance	R _{θJA} (1)(2)	57	°C/W	
Typical thermal resistance	R _{0JM} (3)	0.2	C/VV	

Notes

- $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Free air, mounted on recommended PCB, 2 oz. pad area; thermal resistance R_{BJA} junction to ambient
- (3) Thermal resistance junction-to-mount to follow JEDEC® 51-14 transient dual interface test method (TDIM)

IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)					
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	CLASS	VALUE
AEC-Q101-001	Human body model (contact mode)	$C = 100 \text{ pF}, R = 1.5 \text{ k}\Omega$	V	НЗВ	> 8 kV
IEC 61000-4-2 (2)	Human body model (air discharge mode) (1)	$C = 150 \text{ pF}, R = 330 \Omega$	V_{C}	4	> 30 kV

Notes

- (1) Immerse to IEC 61000-4-2 air discharge mode has a typical performance > 30 kV
- (2) System ESD standard

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SE50124-M3/I	2.56	1	750/reel	13" diameter plastic tape and reel	
SE50124HM3/I ⁽¹⁾	2.56	1	750/reel	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

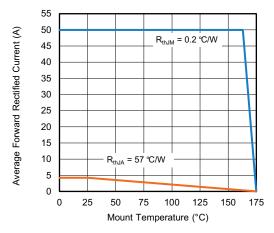


Fig. 1 - Forward Current Derating Curve

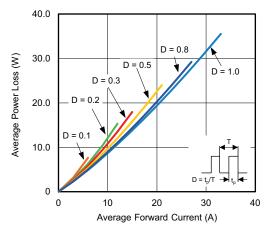


Fig. 2 - Forward Power Loss Characteristics

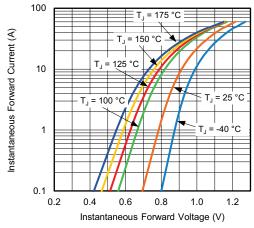


Fig. 3 - Typical Instantaneous Forward Characteristics

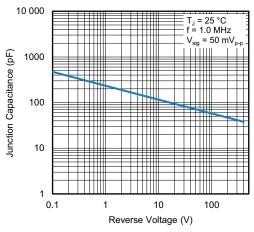


Fig. 4 - Typical Junction Capacitance

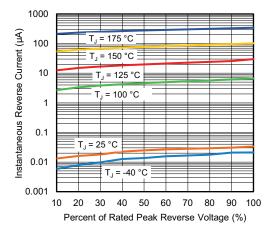


Fig. 5 - Typical Reverse Leakage Characteristics

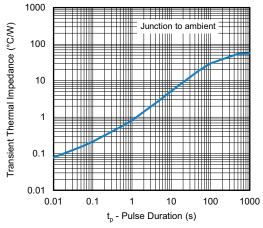
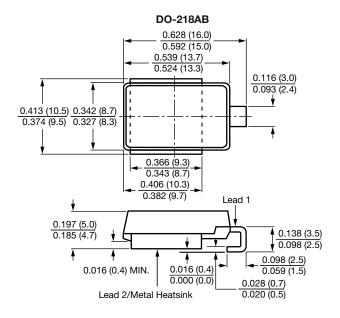
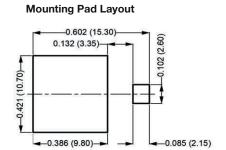


Fig. 6 - Typical Transient Thermal Impedance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Note

• Footprint in accordance with IPC 7351 standard



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